WELLCOMP TECHNOLOGY CO., LTD

APPROVAL SHEET

Model Name	Chip Current Sensing Resistor -High Power Series
Part Number	WCCSH Series
Customer Name	
Customer P/N	
Issued Date	

Customer		Maker		
Approved	Checked	Inspector	Checked	Prepared



元璽科技股份有限公司

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Chip Current Sensing Resistor-High Power

Application

charger

Document No: 20130222001 Issued Date: 2013/02/22

Version: A05

◆Mobile electronic equipment-Cellular phone, NB

◆DC-DC converter, Adapter, Battery pack and

Tablet PC, GPS, DSC, HDD

◆Power management applications

◆Switching power supply◆Voltage Regulation module

Features

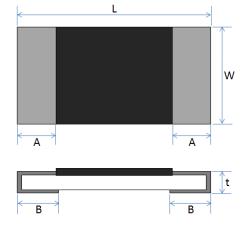
- ♦Chip size from 0603 to 1206
- igspaceResistance Value from 20m Ω to 910m Ω
- ◆Lead free, RoHS compliant for global applications and halogen free

Part Numbering System

<u>WCCSH 1206 R050 F T x</u>

- (1) (2) (3) (4) (5) (6)
- (1) Series Code
- (2) Size (EIA): Length x Width
- (3) Resistance: R002=2m Ω , R010=10m Ω
- (4) Tolerance: D=+/-0.5%, F=+/-1%, G=+/-2%, J=+/-5%
- (5) Packaging: T- Embossed paper tape, 7" reel
 - E-Embossed plastic tape, 7" reel
- (6) Factory Code

Dimension



Туре	Dimensions						
(inch size)	L	W	t	Α	В		
0603	1.55±0.10	0.80±0.10	0.45±0.10	0.30±0.20	0.35±0.20		
0805	2.10±0.15	1.30±0.15	0.65±0.15	0.40±0.20	0.40±0.20		
1206-S Type	2.1010.20	4.65.040	0.65.045	0.50±0.30	0.45+0.30		
1206-L Type	3.10±0.20	1.65±0.10	0.65±0.15	0.8±0.30	0.45±0.20		



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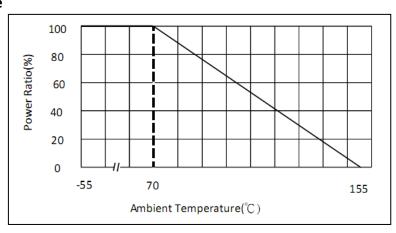
Electrical Specification

	Power		tance Range(Operation	TCR (PPM/	
Туре	Rating	1%	2%	5%	Temp. Range	℃)
0603	1/8W		20~99			±800
0603	1/800		100~499			±200
		6~10				±800
0805	1/4W	11~100			-55~+155℃	±400
			101~976	-55 +155 (±200	
			6~10		±800	
1206	1/2W	11~100				±400
		101~976				±200

Note:

(1) Non-Standard resistance values available

Derating Curve





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Performances

Environmental Performance

No	lkom	Tost Condition	Specification		
No.	Item	Test Condition	1%, 2%	5%	
1	Short Time Overload	5X rated power for 5 sec. (JIS-C5202-5.5)	±(1%+0.05Ω)	±(2%+0.05Ω)	
2	Temperature Coefficient of Resistance (T.C.R.)	+25°C/+125°C. (JIS-C5202-5.2) $TCR \text{ (ppm/°C)} = \frac{\Delta R}{R \times \Delta t} \times 10^{6}$	Refer to Electrical Specification		
3	Damp Heat with Load	The specimens shall be placed in a chamber and subjected to a relative humidity of 90~95% percent and a temperature of 40° ±2°C for the period of 1000 hrs. (MIL-STD-202, Method 103)	±(2%+0.05Ω)	±(3%+0.05Ω)	
4	High Temperature Exposure	The ship (mounted on board) is exposed in the heat chamber 125±3°C for 1000 hrs. (JIS-C5202-7.2)	±(1%+0.05Ω)	±(1.5%+0.05Ω)	
5	Load Life	Apply rated power at 70±2°C for 1000 hours with 1.5 hours ON and 0.5 hour OFF. (JIS-C5202-7.10)	±(2%+0.05Ω)	±(3%+0.05Ω)	
6	Rapid change of temperature	The chip (mounted on board) is exposed, -55±3°C (30min.)/+125±2°C (30min.) for 5 cycles. The following conditions as the following figure. (JIS-C5202-7.4) Ambient temperature 30 min. 30 min. 30 min. 2~3 min.	±(0.5%+0.05Ω)	±(1%+0.05Ω)	



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Function Performance

No	lk a va	Test Condition	Specification		
No.	Item	Test Condition	1%, 2%	5%	
1	Bending Strength	Mount the chip to test substrate. Apply pressure in direction of arrow unit band width reaches 3mm(+0.2/-0mm) illustrated in the figure below and hold for 10±1 sec. (JIS-C5202-6.1) Unit: mm Position before bend Testing printed direuit board	tion of arrow unit band width reaches (+0.2/-0mm) illustrated in the figure below hold for 10±1 sec. (JIS-C5202-6.1) Unit: mm ±(1%+0.05Ω)		
5	Solvent Resistance	The chip is completed immersion of the specimens in the isopropyl alcohol for 3 *+5, -0) min., 25°C ±5°C. (MIL-STD-202, Method 215)	Verify marking per required for laser of parts with no mark	etched parts or	
6	Resistance to solder Heat	The specimen chip shall be immersed into the flux specified in the solder bath 260±5°C for 10±1 sec. (MIL-STD-202, Method 210)	±(0.5%+0.05Ω)	±(1%+0.05Ω)	
7	Solderability	The specimen chip shall be immersed into the flux specified in the solder bath 235±5°C for 2±0.5 sec. It shall be immersed to a point 10mm from its root. (Sn96.5/Ag3.0/Cu0.5) (JIS-C5 202-6.11) Molten solder Specimen Specimen $h = 10 \text{ mm}$ $H = 10 \text{ mm}$ min.	Solder shall be cov of the electrode an		



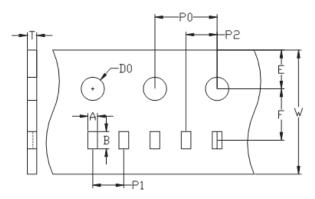
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Tape Packaging Specifications

◆Paper Tape Specifications



Unit:mm

Type	Carrier Dimensions									
Туре	Α	В	E	F	W	P0	P1	P2	D0	Т
0603	1.1±0.1	1.9±0.1	1.75±0.1	3.5±0.05	8.0±0.2	4.0±0.1	4.0±0.1	2.0±0.05	1.55±0.05	0.64±0.1
0805	1.6±0.1	2.4±0.1	1.75±0.1	3.5±0.05	8.0±0.2	4.0±0.1	4.0±0.1	2.0±0.05	1.55±0.05	0.97±0.1
1206	2.0±0.1	3.6±0.1	1.75±0.1	3.5±0.05	8.0±0.2	4.0±0.1	4.0±0.1	2.0±0.05	1.55±0.05	0.97±0.1

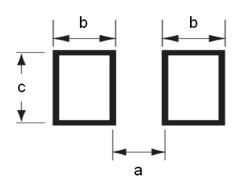
Packaging

Size EIA (EIAJ)	0603/0805/1206
Standard Packing Quantity (pcs /reel)	5,000

Storage Conditions

Temperature : $5^{\circ}35^{\circ}C$, Humidity : $40^{\circ}75\%$

Recommended Solder Pad Layout



Turno	Pad Layout Dimension (mm)						
Туре	a	b	С				
0603	0.90	0.70	1.00				
0805	1.20	1.20	1.40				
1206	2.20	1.30	1.80				



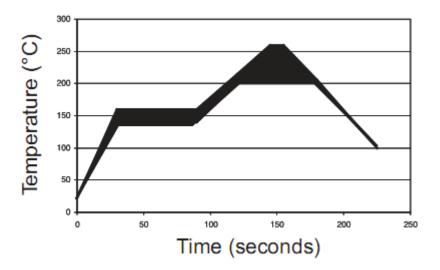
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Soldering Recommendations

- ◆ Peak reflow temperatures and durations:
 - IR Reflow Peak = 260° C max for 10 sec
 - Wave Solder = 260°C max for 10 sec
- ◆ Compatible with lead and lead-free solder reflow processes
- ◆ Recommended IR Reflow Profile :



ECN

Engineering Change Notice: The customer will be informed with ECN if there is significant modification on the characteristics and materials described in Approval Sheet.